PNP Silicon Epitaxial Planar Transistor

for switching and AF amplifier applications

These transistors are subdivided into three groups A, B and C according to their current gain.



1. Collector 2. Base 3. Emitter TO-92 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	r	Symbol	Value	Unit
Collector Base Voltage	BC556 BC557, BC560	-V _{CBO}	80 50	V
	BC558, BC559		30	
Collector Emitter Voltage	BC556 BC557, BC560 BC558, BC559	-V _{CEO}	65 45 30	V
Emitter Base Voltage		-V _{EBO}	5	V
Collector Current (DC)		-I _C	100	mA
Peak Collector Current		-I _{CM}	200	mA
Total Power Dissipation		P_{tot}	500	mW
Junction Temperature		T _j	150	°C
Storage Temperature Range		Ts	- 65 to + 150	°C

Characteristics at T_a = 25 °C

Parameter		Symbol	Min.	Max.	Unit
DC Current Gain at -V _{CE} = 5 V, -I _C = 2 mA Curren	t Gain Group A B C	h _{FE} h _{FE} h _{FE}	110 200 420	220 450 800	- - -
Collector Base Cutoff Current at -V _{CB} = 30 V		-I _{CBO}	-	15	nA
Emitter Base Cutoff Current at -V _{EB} = 5 V		-I _{EBO}	-	100	nA
Collector Base Breakdown Voltage at -I _C = 100 μA	BC556 BC557, BC560 BC558, BC559	-V _{(BR)CBO}	80 50 30	- - -	V
Collector Emitter Breakdown Voltage at -I _C = 2 mA	BC556 BC557, BC560 BC558, BC559	-V _{(BR)CEO}	65 45 30	- - -	V
Emitter Base Breakdown Voltage at $-I_E = 100 \mu A$		-V _{(BR)EBO}	5	-	V









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Characteristics at T_a = 25 °C

Parameter	Symbol	Min.	Max.	Unit
Collector Emitter Saturation Voltage at $-I_C = 10$ mA, $-I_B = 0.5$ mA at $-I_C = 100$ mA, $-I_B = 5$ mA	-V _{CE(sat)}	-	0.3 0.65	V
Base Emitter On Voltage at $-V_{CE} = 5 \text{ V}$, $-I_C = 2 \text{ mA}$ at $-V_{CE} = 5 \text{ V}$, $-I_C = 10 \text{ mA}$	-V _{BE(on)}	0.55	0.75 0.82	V
Transition Frequency at $-V_{CE} = 5 \text{ V}$, $-I_{C} = 10 \text{ mA}$, $f = 100 \text{ MHz}$	f _T	100	-	MHz
Collector Base Capacitance at -V _{CB} = 10 V, f = 1 MHz	C _{cb}	-	6	pF

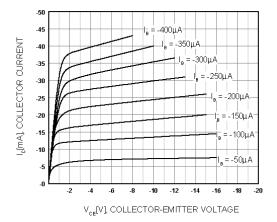


Figure 1. Static Characteristic

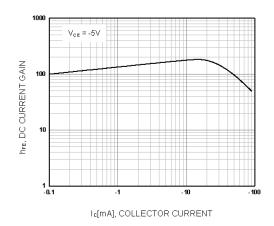


Figure 2. DC current Gain

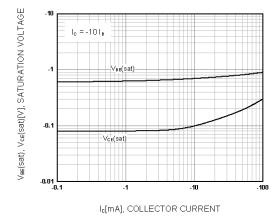


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

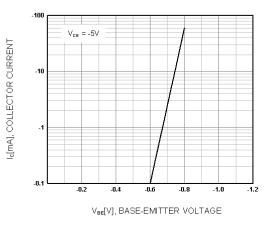


Figure 4. Base-Emitter On Voltage



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Dated: 27/12/2007